

Absolute Maximum Ratings *(Note 1)*

If Military/Aerospace specified devices are required, please contact the National Semiconductor Sales Office/Distributors for availability and specifications.

ESD Tolerance *(Note 2)*

| | |
|--------------------------------------------------------|--------------------------|
| Human Body Model | 1.5kV |
| Machine Model | 150V |
| Differential Input Voltage | ±Supply Voltage |
| Voltage at Input/Output Pin | (V+) +0.4V to (V-) -0.4V |
| Supply Voltage (V+ - V-) | 6V |
| Output Short Circuit V+ | <i>(Note 3)</i> |
| Output Short Circuit V- | <i>(Note 3)</i> |
| Current at Input Pin | ±10mA |
| Current at Output Pin | ±50mA |
| Storage Temp Range | -65°C to 150°C |
| Junction Temperature T _{JMAX} <i>(Note 4)</i> | 150°C |

Soldering specification for LLP SnPb:

Infrared or Convection (20sec)

235°C

Soldering specification for all other packages:

see product folder at www.national.com and

www.national.com/ms/MS/MS-SOLDERING.pdf

Recommended Operating Conditions *(Note 1)*

| | |
|--------------------|-------------------------------|
| Supply Voltage | 2.7V to 5.5V |
| Temperature Range | -40°C ≤ T _J ≤ 85°C |
| Thermal Resistance | |
| 10-Pin MSOP | 235°C/W |
| 10-Pin LLP | 53.4°C/W |
| 10-Bump micro SMD | 196°C/W |

2.7V Electrical Characteristics

Unless otherwise specified, all limits guaranteed for V+ = 2.7V, V- = 0V, V_{CM} = 1.35V and T_A = 25°C and R_L > 1MΩ. **Boldface** limits apply at the temperature extremes.

| Symbol | Parameter | Condition | Min <i>(Note 6)</i> | Typ <i>(Note 5)</i> | Max <i>(Note 6)</i> | Units | |
|--------------------|------------------------------|--------------------------------------------------------|------------------------|------------------------|------------------------|---------------------|----|
| V _{OS} | Input Offset Voltage | V _{CM} = 0.85V and V _{CM} = 1.85V | MSOP | | 0.4 | 3 | mV |
| | | | LLP | | | 3.2 | |
| | | | μSMD | | 3 | 7 9 | |
| I _B | Input Bias Current | | | 5.5 | 115 130 | pA | |
| CMRR | Common Mode Rejection Ratio | 0V ≤ V _{CM} ≤ 2.7V | 50 45 | 75 | | dB | |
| PSRR | Power Supply Rejection Ratio | 2.7V ≤ V+ ≤ 5V, V _{CM} = 0.85V | 70 68 | 90 | | dB | |
| | | 2.7V ≤ V+ ≤ 5V, V _{CM} = 1.85V | 70 68 | 90 | | dB | |
| CMVR | Common Mode Voltage Range | For CMRR ≥ 50dB | | -0.3 | -0.2 | V | |
| | | | | 2.9 | 3 | | |
| I _{SC} | Output Short Circuit Current | Sourcing V _O = 0V | 15 12 | 25 | | mA | |
| | | Sinking V _O = 2.7V | 25 22 | 50 | | mA | |
| V _O | Output Swing | R _L = 10kΩ to 1.35V | | 2.62 2.60 | 2.68 | V | |
| | | | | | 0.01 | 0.12 0.15 | V |
| | | R _L = 600Ω to 1.35V | | 2.52 2.50 | 2.55 | V | |
| | | | | | 0.05 | 0.23 0.30 | V |
| V _{O(SD)} | Output Voltage in Shutdown | | | 10 | 200 | mV | |
| I _S | Supply Current per Channel | On Mode | | 1.22 | 1.7 1.9 | mA | |
| | | Shutdown Mode | | 0.12 | 1.5 2.0 | μA | |

| Symbol | Parameter | Condition | Min (Note 6) | Typ (Note 5) | Max (Note 6) | Units |
|------------------|------------------------------|---------------------------------------------------------------------|-----------------|-----------------|-----------------|--------|
| A _{VOL} | Large Signal Voltage Gain | Sourcing R _L = 10kΩ V _O = 1.35V to 2.3V | 80 76 | 115 | | dB |
| | | Sinking R _L = 10kΩ V _O = 0.4V to 1.35V | 80 76 | 113 | | dB |
| | | Sourcing R _L = 600Ω V _O = 1.35V to 2.2V | 80 76 | 97 | | dB |
| | | Sinking R _L = 600Ω V _O = 0.5V to 1.35V | 80 76 | 100 | | dB |
| V _{SD} | Shutdown Pin Voltage Range | On Mode | 2.4 to 2.7 | 2.0 to 2.7 | | V |
| | | Shutdown Mode | 0 to 0.8 | 0 to 1 | | V |
| GBWP | Gain-Bandwidth Product | | | 5 | | MHz |
| SR | Slew Rate | (Note 7) | | 5 | | V/μs |
| φ _m | Phase Margin | | | 60 | | Deg |
| e _n | Input Referred Voltage Noise | f = 1kHz | | 20 | | nV/√Hz |
| T _{ON} | Turn-On Time from Shutdown | | | 2.2 | 4 4.6 | μs |
| | Turn-On Time from Shutdown | micro SMD | 6 8 | | | μs |

5V Electrical Characteristics

Unless otherwise specified, all limits guaranteed for V⁺ = 5V, V⁻ = 0V, V_{CM} = 2.5V and T_A = 25°C and R_L > 1MΩ. **Boldface** limits apply at the temperature extremes.

| Symbol | Parameter | Condition | Min (Note 6) | Typ (Note 5) | Max (Note 6) | Units | |
|-----------------|------------------------------|--------------------------------------------------------|-----------------|-----------------|-----------------|-----------------|-------------------|
| V _{OS} | Input Offset Voltage | V _{CM} = 0.85V and V _{CM} = 1.85V | MSOP LLP | | 0.4 | 3 3.2 | mV |
| | | | μSMD | | 3 | 7 9 | |
| | | | | | | 5.5 | 115 130 |
| CMRR | Common Mode Rejection Ratio | 0V ≤ V _{CM} ≤ 5V | 50 45 | 80 | | dB | |
| PSRR | Power Supply Rejection Ratio | 2.7V ≤ V ⁺ ≤ 5V, V _{CM} = 0.85V | 70 68 | 90 | | dB | |
| | | 2.7V ≤ V ⁺ ≤ 5V, V _{CM} = 1.85V | 70 68 | 90 | | dB | |
| CMVR | Common Mode Voltage Range | For CMRR ≥ 50dB | | -0.3 | -0.2 | V | |
| | | | | 5.2 | 5.3 | V | |
| I _{SC} | Output Short Circuit Current | Sourcing V _O = 0V | 20 18 | 35 | | mA | |
| | | Sinking V _O = 5V | 25 21 | 50 | | mA | |

| Symbol | Parameter | Condition | Min (Note 6) | Typ (Note 5) | Max (Note 6) | Units |
|-----------|------------------------------|-------------------------------------------------------|---------------------|-----------------|---------------------|----------------|
| V_O | Output Swing | $R_L = 10k\Omega$ to 2.5V | 4.92 4.90 | 4.98 | | V |
| | | | | 0.01 | 0.12 0.15 | V |
| | | $R_L = 600\Omega$ to 2.5V | 4.82 4.80 | 4.85 | | V |
| | | | | 0.05 | 0.23 0.30 | V |
| $V_O(SD)$ | Output Voltage in Shutdown | | 10 | 200 | mV | |
| I_S | Supply Current per Channel | On Mode | | 1.17 | 1.7 1.9 | mA |
| | | Shutdown Mode | | 0.12 | 1.5 2.0 | μ A |
| A_{VOL} | Large Signal Voltage Gain | Sourcing $R_L = 10k\Omega$ $V_O = 2.5V$ to 4.6V | 80 76 | 130 | | dB |
| | | Sinking $R_L = 10k\Omega$ $V_O = 0.4V$ to 2.5V | 80 76 | 130 | | dB |
| | | Sourcing $R_L = 600\Omega$ $V_O = 2.5V$ to 4.6V | 80 76 | 110 | | dB |
| | | Sinking $R_L = 600\Omega$ $V_O = 0.4V$ to 2.5V | 80 76 | 107 | | dB |
| V_{SD} | Shutdown Pin Voltage Range | On Mode | 4.5 to 5 | 3.5 to 5 | | V |
| | | Shutdown Mode | 0 to 0.8 | 0 to 1.5 | | V |
| GBWP | Gain-Bandwidth Product | | | 5 | | MHz |
| SR | Slew Rate | (Note 7) | | 5 | | V/ μ s |
| ϕ_m | Phase Margin | | | 60 | | Deg |
| e_n | Input Referred Voltage Noise | $f = 1kHz$ | | 20 | | nV/\sqrt{Hz} |
| T_{ON} | Turn-On Time for Shutdown | | | 1.6 | 4 4.6 | μ s |
| | Turn-On Time for Shutdown | micro SMD | 6 8 | | | μ s |

Note 1: Absolute Maximum Ratings indicate limits beyond which damage to the device may occur. Operating Ratings indicate conditions for which the device is intended to be functional, but specific performance is not guaranteed. For guaranteed specifications and the test conditions, see the *Electrical Characteristics*.

Note 2: Human Body Model, applicable std. MIL-STD-883, Method 3015.7. Machine Model, applicable std. JESD22-A115-A (ESD MM std. of JEDEC). Field-Induced Charge-Device Model, applicable std. JESD22-C101-C (ESD FICDM std. of JEDEC).

Note 3: Shorting circuit output to either V+ or V- will adversely affect reliability.

Note 4: The maximum power dissipation is a function of $T_{J(MAX)}$, θ_{JA} . The maximum allowable power dissipation at any ambient temperature is $P_D = (T_{J(MAX)} - T_A) / \theta_{JA}$. All numbers apply for packages soldered directly onto a PC Board.

Note 5: Typical values represent the most likely parametric norm as determined at the time of characterization. Actual typical values may vary over time and will also depend on the application and configuration. The typical values are not tested and are not guaranteed on shipped production material.

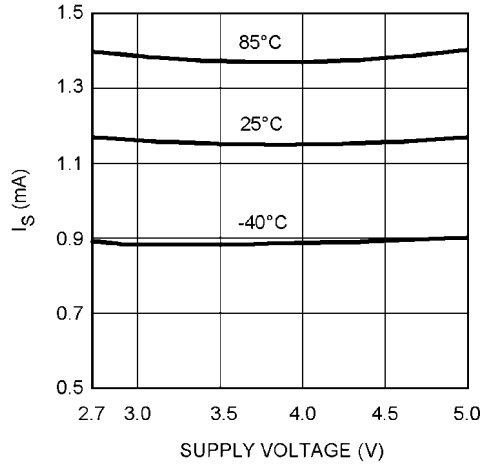
Note 6: All limits are guaranteed by testing or statistical analysis.

Note 7: Number specified is the slower of the positive and negative slew rates.

Typical Performance Characteristics

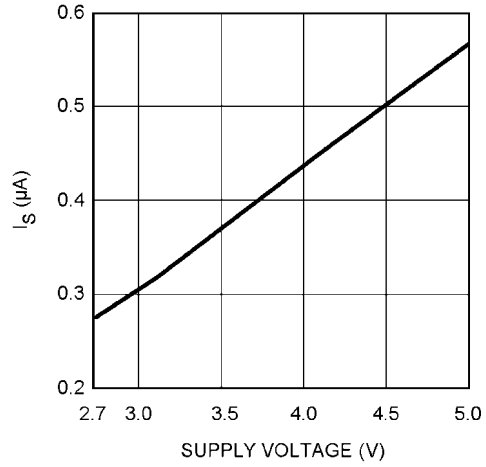
Unless otherwise specified, $V_S = +5V$, single supply, $T_A = 25^\circ C$.

Supply Current Per Channel vs. Supply Voltage



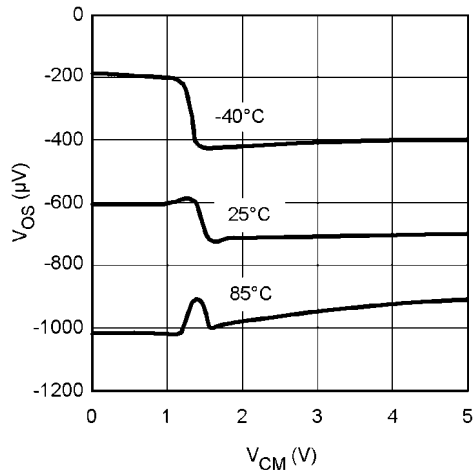
10137001

Supply Current vs. Supply Voltage (Shutdown)



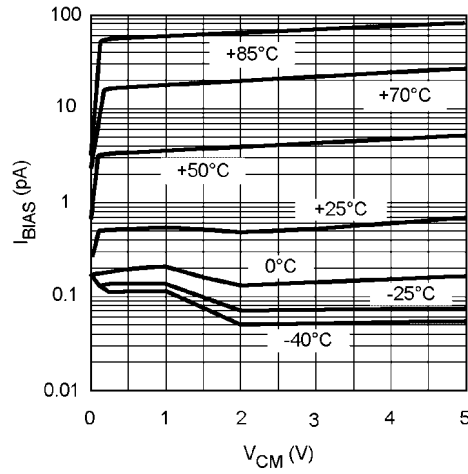
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V_{OS} vs. V_{CM}



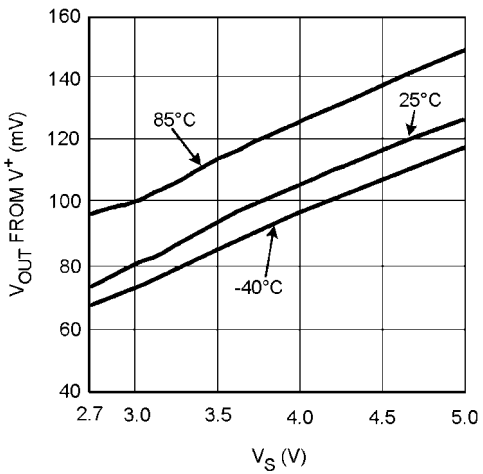
10137003

I_B vs. V_{CM} Over Temp



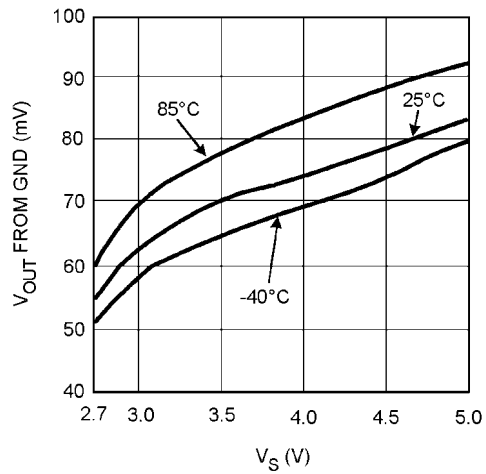
10137005

Output Positive Swing vs. Supply Voltage, $R_L = 600\Omega$



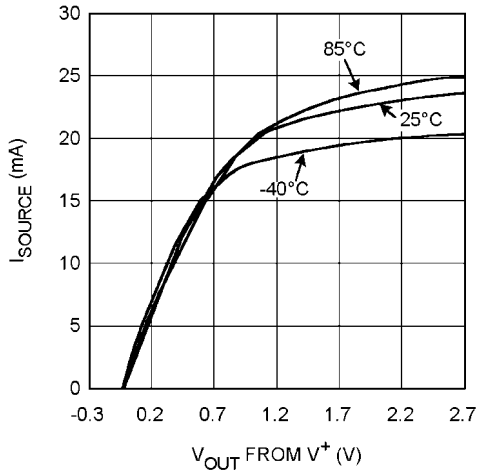
10137006

Output Negative Swing vs. Supply Voltage, $R_L = 600\Omega$



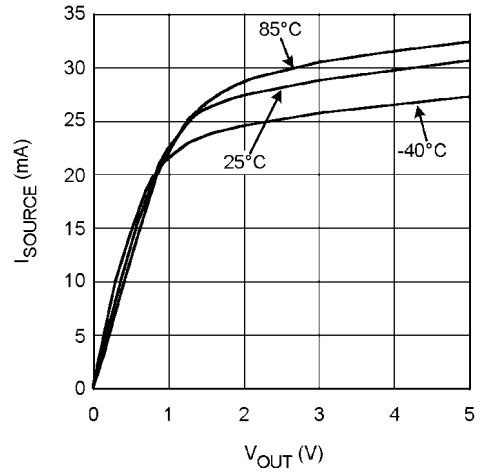
10137007

Sourcing Current vs. Output Voltage, $V_S = 2.7V$



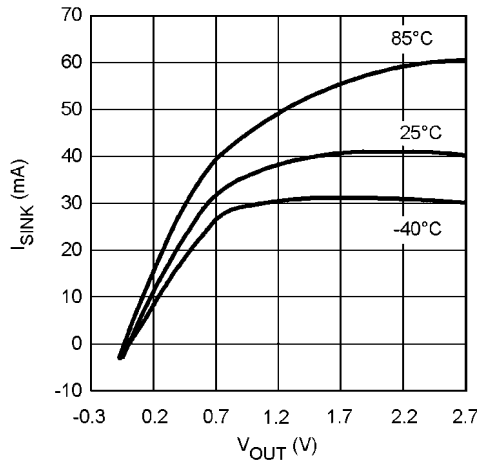
10137008

Sourcing Current vs. Output Voltage, $V_S = 5V$



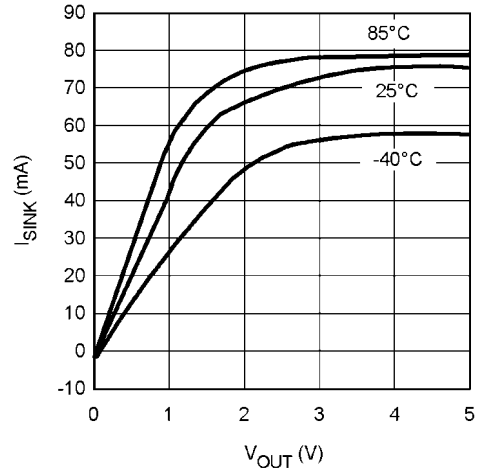
10137010

Sinking Current vs. Output Voltage, $V_S = 2.7V$



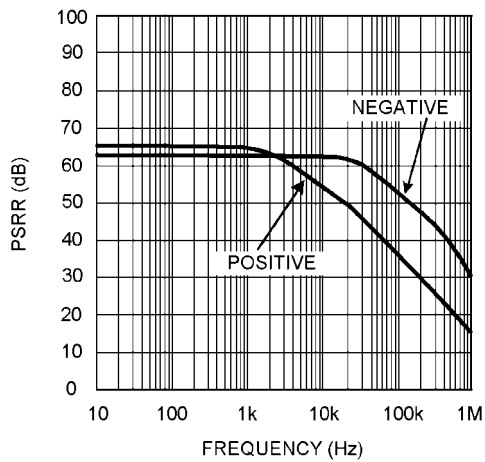
10137009

Sinking Current vs. Output Voltage, $V_S = 5V$



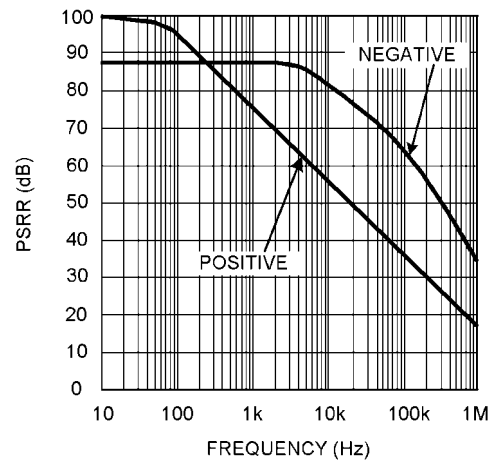
10137011

PSRR vs. Frequency $V_S = 2.7V$

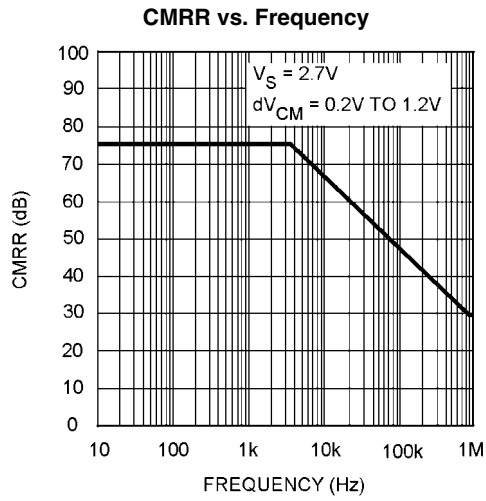


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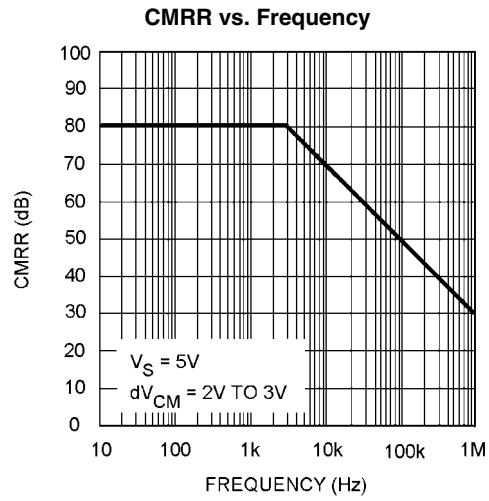
PSRR vs. Frequency $V_S = 5V$



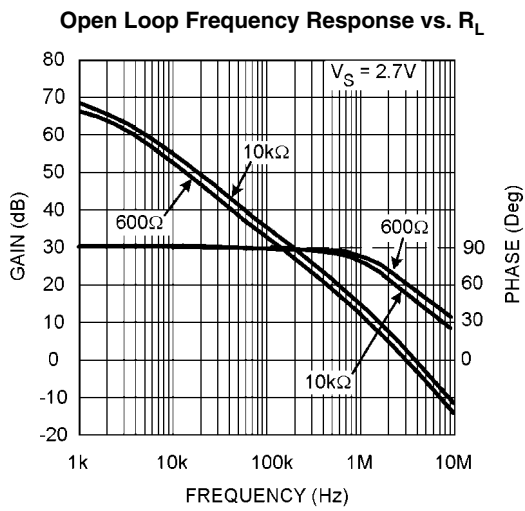
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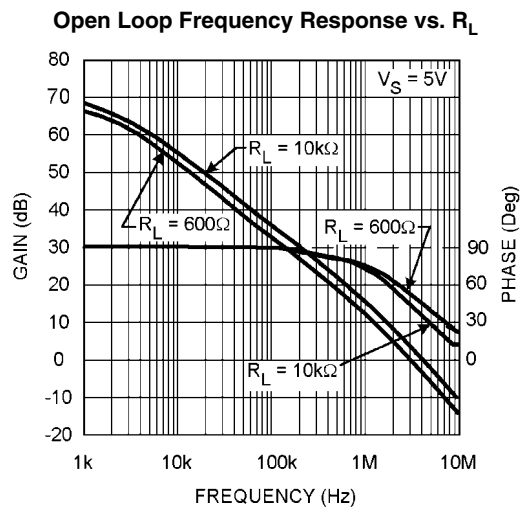
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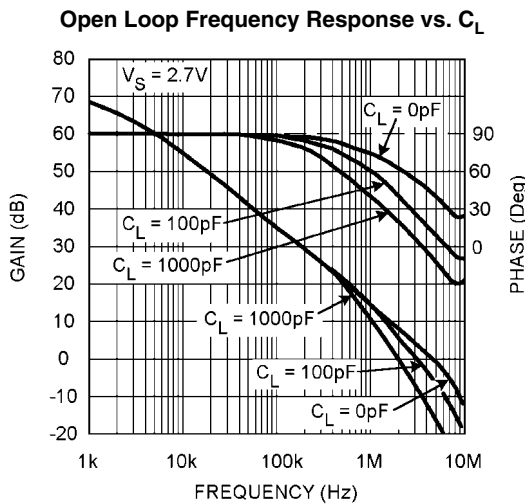
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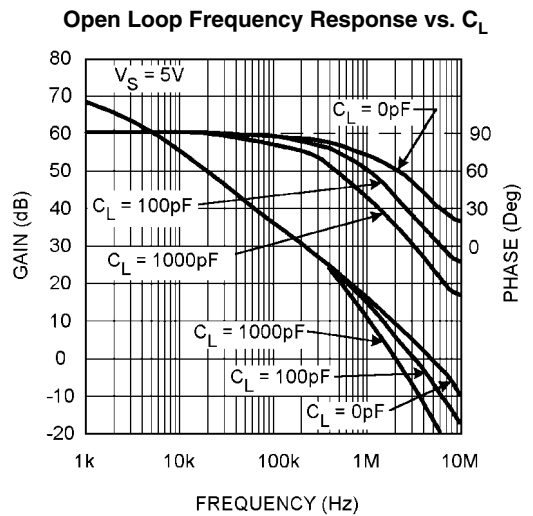
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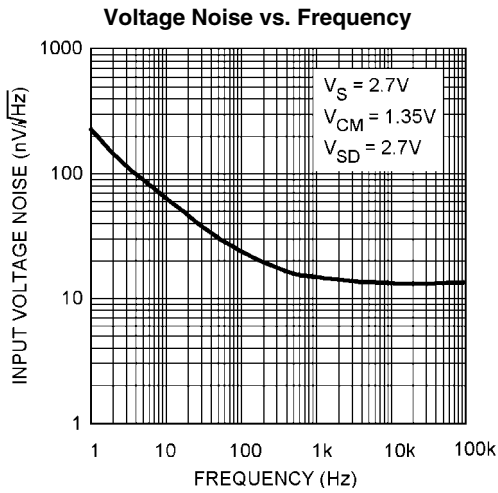
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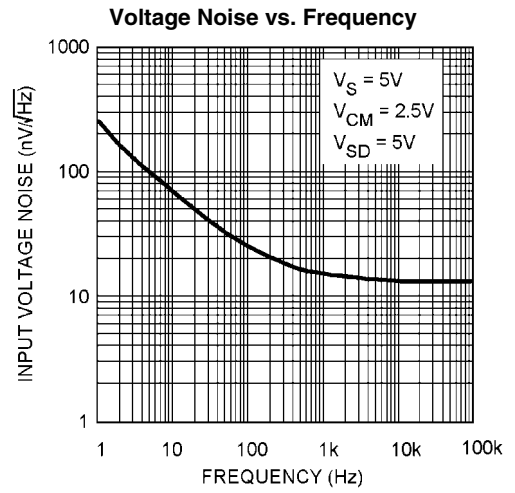
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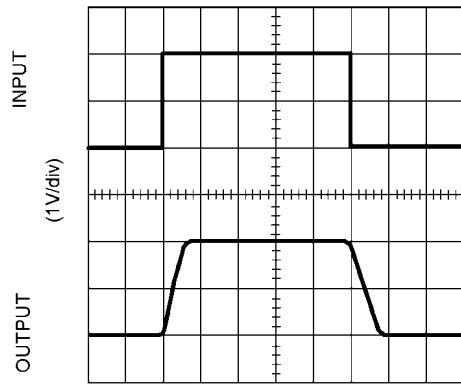


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10137021

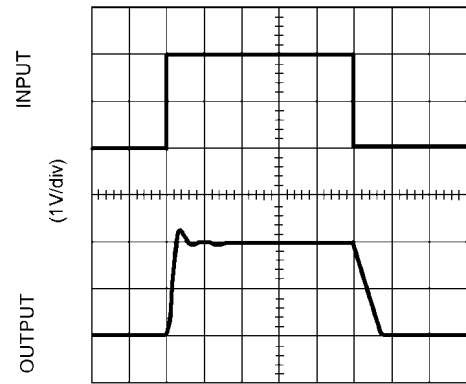
Non-Inverting Large Signal Pulse Response, $V_S = 2.7V$



TIME (500ns/div)

10137022

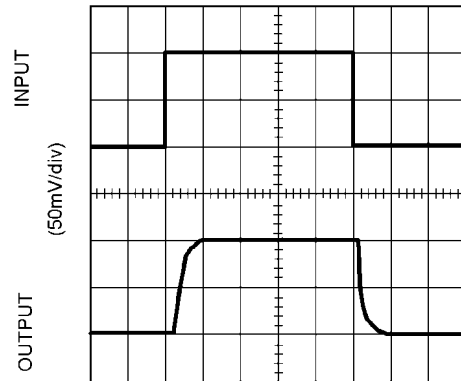
Non-Inverting Large Signal Pulse Response, $V_S = 5V$



TIME (500ns/div)

10137024

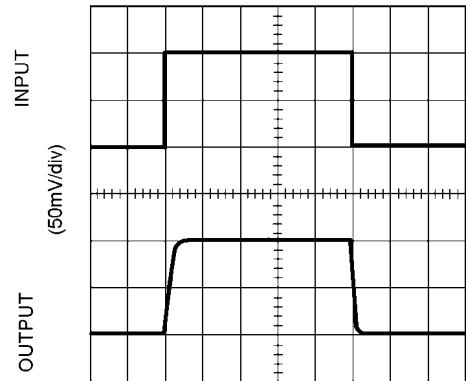
Non-Inverting Small Signal Pulse Response, $V_S = 2.7V$



TIME (500ns/div)

10137023

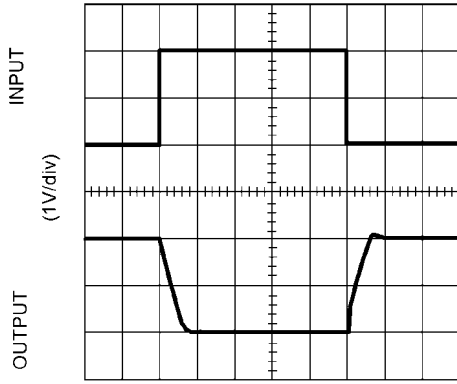
Non-Inverting Small Signal Pulse Response, $V_S = 5V$



TIME (500ns/div)

10137025

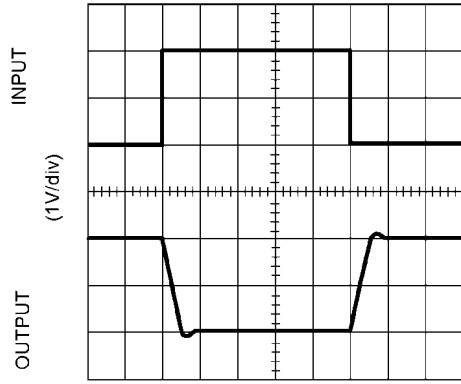
Inverting Large Signal Pulse Response, $V_S = 2.7V$



TIME (500ns/div)

10137026

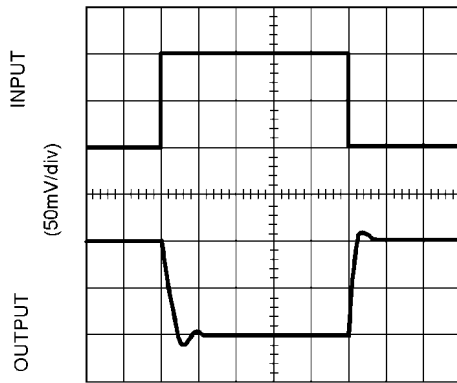
Inverting Large Signal Pulse Response, $V_S = 5V$



TIME (500ns/div)

10137028

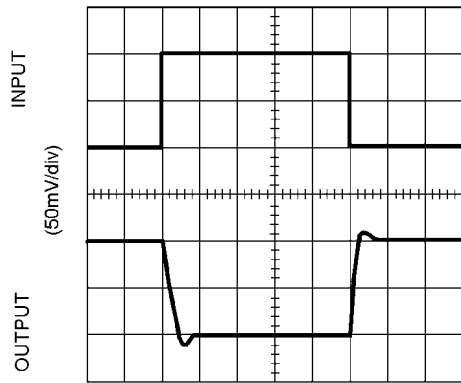
Inverting Small Signal Pulse Response, $V_S = 2.7V$



TIME (500ns/div)

10137027

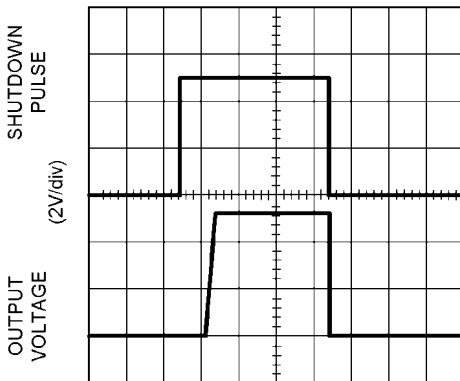
Inverting Small Signal Pulse Response $V_S = 5V$



TIME (500ns/div)

10137029

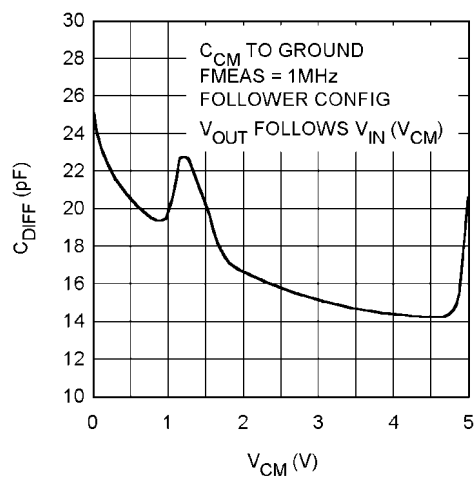
Turn on Time Response $V_S = 5V$



TIME (2μs/div)

10137030

Input Common Mode Capacitance vs. V_{CM} $V_S = 5V$

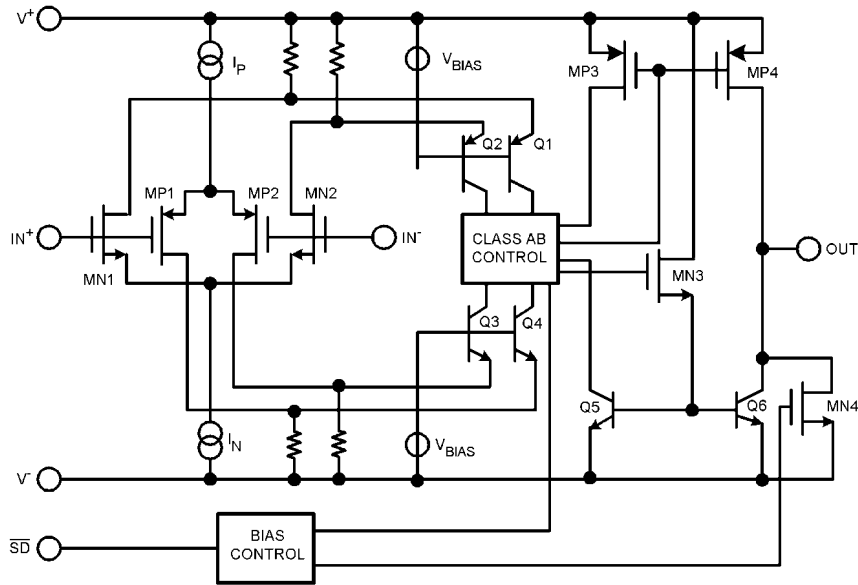


10137004

Application Information

THEORY OF OPERATION

The LMV712 dual op amp is derived from the LMV711 single op amp. *Figure 1* contains a simplified schematic of one channel of the LMV712.



10137031

FIGURE 1.

Rail-to-Rail input is achieved by using in parallel, one NMOS differential pair (MN1 and MN2) and one PMOS differential pair (MP1 and MP2). When the common mode input voltage (V_{CM}) is near V^+ , the NMOS pair is on and the PMOS pair is off. When V_{CM} is near V^- , the NMOS pair is off and the PMOS pair is on. When V_{CM} is between V^+ and V^- , internal logic decides how much current each differential pair will get. This special logic ensures stable and low distortion amplifier operation within the entire common mode voltage range.

Because both input stages have their own offset voltage (V_{OS}) characteristic, the offset voltage of the LMV712 becomes a function of V_{CM} . V_{OS} has a crossover point at 1.4V above V^- . Refer to the " V_{OS} vs. V_{CM} " curve in the Typical Performance Characteristics section. Caution should be taken in situations where input signal amplitude is comparable to V_{OS} value and/or the design requires high accuracy. In these situations, it is necessary for the input signal to avoid the crossover point.

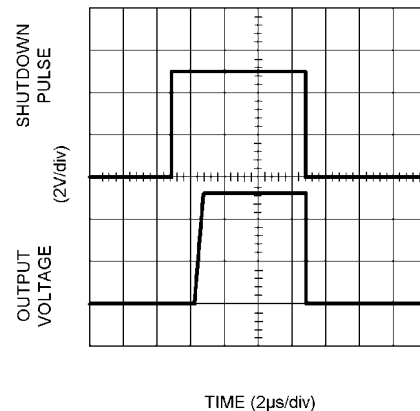
The current coming out of the input differential pairs gets mirrored through two folded cascode stages (Q1, Q2, Q3, Q4) into the "class AB control" block. This circuitry generates voltage gain, defines the op amp's dominant pole and limits the maximum current flowing at the output stage. MN3 introduces a voltage level shift and acts as a high impedance to low impedance buffer.

The output stage is composed of a PMOS and a NPN transistor in a common source/emitter configuration, delivering a rail-to-rail output excursion.

The MN4 transistor ensures that the LMV712 output remains near V^- when the amplifier is in shutdown mode.

SHUTDOWN PIN

The LMV712 offers independent shutdown pins for the dual amplifiers. When the shutdown pin is tied low, the respective amplifier shuts down and the supply current is reduced to less than $1\mu\text{A}$. In shutdown mode, the amplifier's output level stays at V^- . In a 2.7V operation, when a voltage between 1.5V to 2.7V is applied to the shutdown pin, the amplifier is enabled. As the amplifier is coming out of the shutdown mode, the output waveform ramps up without any glitch. This is demonstrated in *Figure 2*.



10137030

FIGURE 2.

A glitch-free output waveform is highly desirable in many applications, one of which is power amplifier control loops. In this application, the LMV712 is used to drive the power amplifier's power control. If the LMV712 did not have a smooth output ramp during turn on, it would directly cause the power amplifier to produce a glitch at its output. This adversely affects the performance of the system.

To enable the amplifier, the shutdown pin must be pulled high. It should not be left floating in the event that any leakage current may inadvertently turn off the amplifier.

PRINTED CIRCUIT BOARD CONSIDERATION

To properly bypass the power supply, several locations on a printed circuit board need to be considered. A 6.8 μ F or greater tantalum capacitor should be placed at the point where the power supply for the amplifier is introduced onto the board. Another 0.1 μ F ceramic capacitor should be placed as close as possible to the power supply pin of the amplifier. If the amplifier is operated in a single power supply, only the V+ pin needs to be bypassed with a 0.1 μ F capacitor. If the amplifier is operated in a dual power supply, both V+ and V- pins need to be bypassed.

It is good practice to use a ground plane on a printed circuit board to provide all components with a low inductive ground connection.

Surface mount components in 0805 size or smaller are recommended in the LMV712 application circuits. Designers can take advantage of the micro SMD, MSOP and LLP miniature sizes to condense board layout in order to save space and reduce stray capacitance.

CAPACITIVE LOAD TOLERANCE

The LMV712 can directly drive 200pF in unity-gain without oscillation. The unity-gain follower is the most sensitive configuration to capacitive loading. Direct capacitive loading reduces the phase margin of amplifiers. The combination of the amplifier's output impedance and the capacitive load induces phase lag. This results in either an under-damped pulse response or oscillation. To drive a heavier capacitive load, [Figure 3](#) can be used.

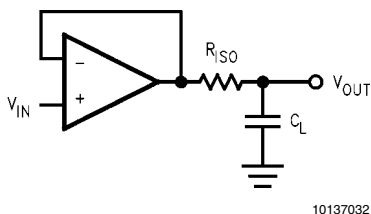


FIGURE 3.

In [Figure 3](#), the isolation resistor R_{ISO} and the load capacitor C_L form a pole to increase stability by adding more phase margin to the overall system. The desired performance depends on the value of R_{ISO} . The bigger the R_{ISO} resistor value, the more stable V_{OUT} will be. But the DC accuracy is degraded when the R_{ISO} gets bigger. If there were a load resistor in [Figure 3](#), the output voltage would be divided by R_{ISO} and the load resistor.

The circuit in [Figure 4](#) is an improvement to the one in [Figure 3](#) because it provides DC accuracy as well as AC stability. In this circuit, R_F provides the DC accuracy by using feed-forward techniques to connect V_{IN} to R_L . C_F and R_{ISO} serve to counteract the loss of phase margin by feeding the high frequency component of the output signal back to the amplifier's inverting input, thereby preserving phase margin in the overall feedback loop. Increased capacitive drive is possible by increasing the value of C_F . This in turn will slow down the pulse response.

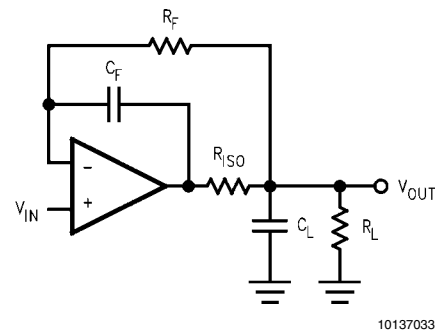
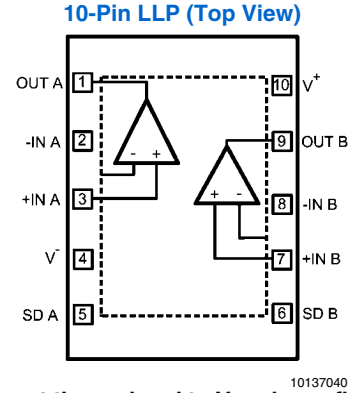
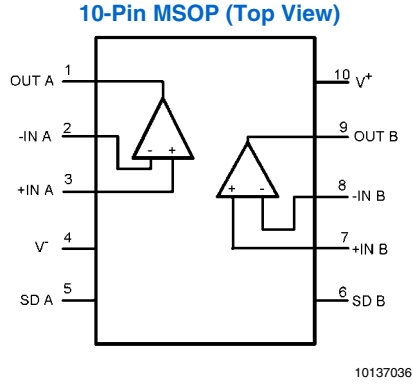


FIGURE 4.

LATCHUP

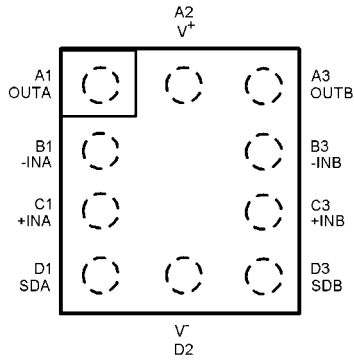
CMOS devices tend to be susceptible to latchup due to their internal parasitic SCR (silicon controlled rectifier) effects. The input and output pins look similar to the gate of the SCR. There is a minimum current required to trigger the SCR gate lead. The LMV712 is designed to withstand 150mA surge current on all the pins. Some resistive method should be used to isolate any capacitance from supplying excess current to the pins. In addition, like an SCR, there is a minimum holding current for any latchup mode. Limiting current to the supply pins will also inhibit latchup susceptibility.

Connection Diagrams

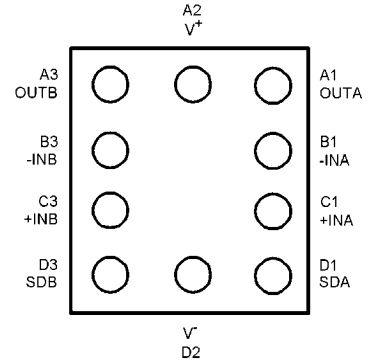


*Connect thermal pad to V- or leave floating

10-Bump micro SMD (Top View)



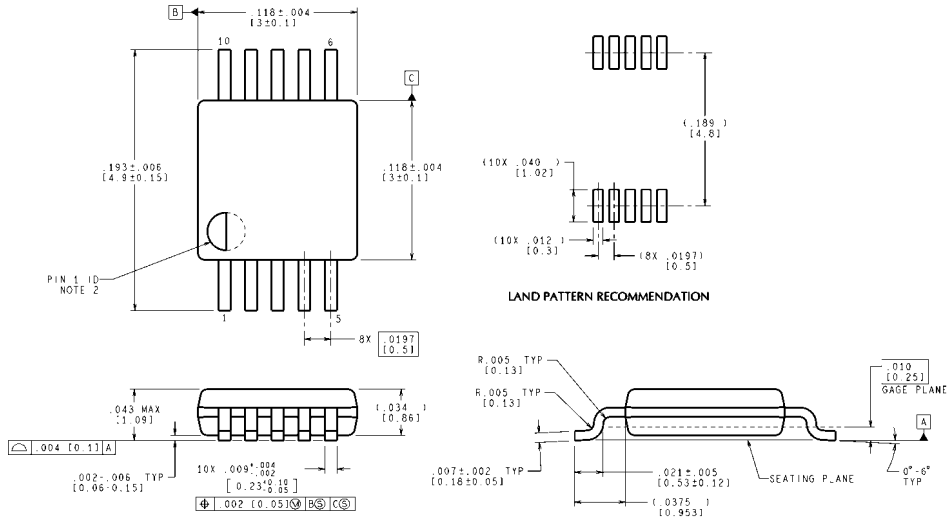
10-Bump micro SMD (Bottom View)



Ordering Information

| Package | Part Number | Package Marking | Transport Media | NSC Drawing |
|--------------------------|-------------|-----------------|--------------------------|---------------------------|
| 10-Pin MSOP | LMV712MM | A61 | 1k Units Tape and Reel | MUB10A |
| | LMV712MMX | | 3.5k Units Tape and Reel | |
| 10-Pin LLP | LMV712LD | A62 | 1k Units Tape and Reel | LDA10A |
| | LMV712LDX | | 4.5k Units Tape and Reel | |
| 10-Bump micro SMD (NOPB) | LMV712TL | AU2A | 250 Units Tape and Reel | TLP10BBA 0.600mm thick |
| | LMV712TLX | | 3k Units Tape and Reel | |

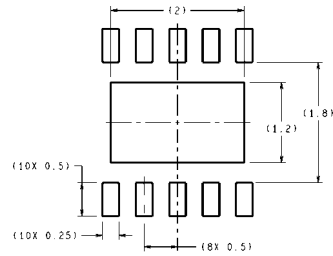
Physical Dimensions inches (millimeters) unless otherwise noted



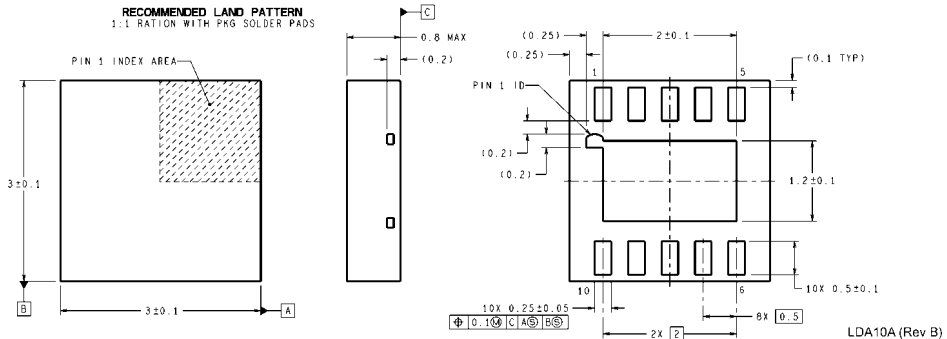
CONTROLLING DIMENSION IS INCH
 VALUES IN [] ARE MILLIMETERS
 DIMENSIONS IN [] FOR REFERENCE ONLY

10-Pin MSOP
NS Package Number MUB10A

MUB10A (Rev B)



DIMENSIONS ARE IN MILLIMETERS



10-Pin LLP
NS Package Number LDA10A

LDA10A (Rev B)

Notes

LMV712

Notes

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